A nom alous low tem perature state of C eO s4Sb12: M agnetic eld and La-im purity study

C.R.Rotundu and B.Andraka Department of Physics, University of Florida P.O.Box 118440, Gainesville, Florida 32611-8440, USA (Dated: April 14, 2024)

Speci c heat for single crystalline sam ples of $C \in x La_x O s_4 Sb_{12}$ at zero-eld and magnetic elds to 14 T is reported. Our results con m enhanced value of the electronic speci c heat coe cient in the param agnetic state. They provide arguments for the intrinsic origin of the 1.1 K anomaly. This transition leads to opening of the gap at the Ferm i surface. This low temperature state of $C eO s_4 Sb_{12}$ is extremely sensitive to chemical in purities. 2 % of La substituted for C e suppresses the transition and reduces the electronic speci c heat coe cient. The magnetic eld response of the speci c heat is also anom alous.

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I. IN TRODUCTION

Filled skuttenudites with a chem ical form ulae RT₄X₁₂, where R is a rare earth, T transition m etal and X = P, As, or Sb, have been lately of great interest due to their broad spectrum of exotic properties related to the unique crystal structure. Am ong them, PrO s₄Sb₁₂ is the rst heavy ferm ion superconductor based on Pr.¹ PrFe₄P₁₂ is a eld induced heavy ferm ion com pound.² C eRu₄Sb₁₂ is a non-Ferm i liquid system.³ C eO s₄Sb₁₂ is a possible K ondo insulator.⁴ T his last m aterial is the least studied and the interpretation of its properties is controversial.

The resistivity of CeO s_4Sb_{12} is metallic at room temperature, but show s behavior typical of an insulator, i.e., increases strongly with a decrease of temperature, below 50 K. The resistivity does not follow an activation-type temperature variation. However, such a variation would be expected only at temperaturesm uch lower than the energy gap of approxim ately 10 K.⁴ There is an evidence that under the hydrostatic pressure of order 8 G Pa, the resistivity evolves into a variable-range hoping type.⁵ A recent study of optical conductivity spectra⁶ shows a strong temperature dependence and a gap of 30 m eV below 60 K. In addition, a structure observed at 70 m eV was interpreted in terms of the hybridization gap peak. These transport properties are quite consistent with a K ondo insulator or hybridization gap sem iconductor.⁷

On the other hand, the two reported values of the electronic speci c heat coe cient, , are 90^4 and $180 \text{ m J/K}^2\text{m ol}^8$, hardly consistent with the presence of an energy gap. The speci c heat also exhibits an anom aly near 1.1 K.Because of a very sm all entropy associated with this anom aly (about 2 % of R ln2 on ly), it has been initially ascribed to some in purity phase⁴. However, the subsequent m agnetic eld study⁸ up to 4 T has undermined this original interpretation.

To shed m one light on the nature of the ground state in $C \in S_4Sb_12$, we have extended the speci c heat m easurements to elds as large as 14 T and introduced Laim purifies on C e sites.

II. EXPERIMENTAL AND RESULTS

Single crystalline samples of $Ce_{1x} La_x Os_4 Sb_{12}$, with x = 0;0:02; and 0.1, were obtained by the Sb-self ux m ethod described elsew here.⁴ For m ixed alloys, Ce and Lawere premelted rst to assure the hom ogeneity of sam ples. X-ray di raction m easurem ents were perform ed on pow dered single crystals using Philips APD 3720 di ractom eter. All spectra were indexed by the BCC (Im $\overline{3}$) crystal structure. No external phases were detected. The change of the lattice constants between the endcom pounds, $C \in O s_4 Sb_{12}$ and LaO $s_4 Sb_{12}$, is very sm all is very small and on the edge of our experimental resolution. These lattice constants are, 9.304(2) and 9.309(2) A, respectively. On the other hand, any variation of the lattice constant between x = 0 and 0.1 is too sm all to be reliably resolved by this technique. This insensitivity of the lattice constant of RO s4Sb12 to the atom ic size of R is a unique property of this crystal structure.^{4,9} A C e ion in CeOs₄Sb₁₂ is surrounded by an oversized icosahedral cage form ed by 12 Sb ions. Thus, only sm all variations of the hybridization parameters upon La-doping are expected.

The results of the magnetic eld study of the pure compound are shown in Fig. 1. The comparison of all up-to-date speci c heat m easurem ents indicates strong sam ple dependency. Our data, in the form of C=T (speci c heat divided by tem perature) versus T, exhibit a peak at $T_m = 1.1 \text{ K}$, thus at a tem perature identical to that reported by Bauer et al⁴. Nam iki et al.⁸, on the other hand, found this peak at 0.9 K . Furtherm ore, the height of the peak is approximately 220, 510, and 380 m J/m olK² according to Bauer et al., Nam ikiet al., and our data, respectively. There is also a large discrepancy in C = T results above the anomaly. Our data above 3 K are consistent with those of Namiki et al., yielding an electronic speci c heat coe cient of 180 m J/m ol K^2 . This high tem perature is reduced by the 1.1 K transition to a value smaller than 100 m J/m ol K 2 . A linear extrapolation of our low est tem perature data (in the form of C=T versus T) in plies that this low tem pera-

FIG.1: C=T versus T for CeO s_4 Sb₁₂ in H=0, 5, 10, and 14 T.M agnetic eld was applied along (100) direction.

might be in fact 0. However, lower temperature ture data are needed to make a more quantitative prediction. Note that results presented in Fig. 1 exclude a nuclear contribution. This nuclear contribution can be separated easily from the electronic one in the relaxation-method calorim etry, if the two characteristic tim e constants entering the measurem ent, characterizing the coupling between electronic degrees of freedom and the heat reservoir and the nuclear spin-lattice relaxation time T₁, determ ining the coupling between nuclear and electronic degrees of freedom , di er substantially 10 Because of a small mass of the single crystal (about 5 mg), this rst tim e constant (0.1 s) was more than the order of m agnitude sm aller than T_1 .

This strong impact of the transition on the linear specience cient is an obvious indication that either the transition itself is intrinsic to CeO s₄Sb₁₂ or that both the anomaly and large high temperature are due to an extrinsic phase. This second scenario is unlikely since this extrinsic phase would have to be a much larger fraction of the sample than initially assumed.⁴ A similar conclusion was reached by N amikiet al., using the specinc heat data at 4 T and a similar argument of the reduction of at T_m . An additional evidence supporting the rest scenario is provided by the impurity study discussed below. Thus the 1.1 K transition leads to a further (possibly full) opening of the gap at the Fermi energy.

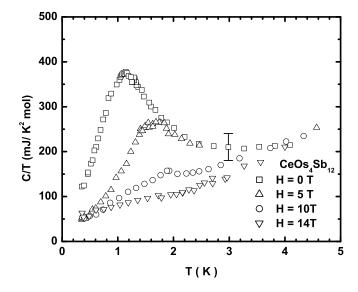
In agreem ent with previous reports,^{8,11} we nd that a moderately strong magnetic eld (5 T; applied along the (100) crystallographic direction) shifts the anomaly to a higher tem perature, but at the same time, the magnitude of the peak is reduced. Again, the extrapolation of the lowest tem perature data to T = 0 yields a small elec-

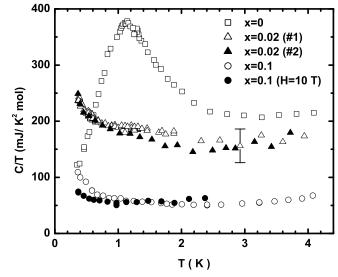
FIG.2: C=T versus T for Ce_{1 x} La_xOs₄Sb₁₂; where x = 0, 0.02, and 0.1 (H = 0 and 10 T).

tronic speci c heat coe cient, much smaller than that corresponding to the param agnetic state. This eld has a negligible e ect on the high tem perature . The anomaly at 10 T is very small, but there is a distinct change of the slope of C =T versus T data at $T_{\rm m}$, in plying a reduction of . On the other hand, we do not detect, within the resolution of our measurement, any anomaly at 14 T.

The eld dependence of the speci c heat is puzzling for the K ondo insulator scenario.⁷ C onsidering the data above the anomaly only, we nd a sizable decrease of the Sommerfeld coe cient with a eld larger than 5 T. In a typical K ondo insulator the opposite is observed.¹² M agnetic eld destroys the hybridization between f- and conduction-electrons that should result in the closing of the gap and an increase of . On the other hand, our C=T data below $T_{\rm m}$, extrapolated to T = 0, suggest that there is a slight increase of the low temperature with m agnetic eld. This trend is clear upon a closer inspection of the data below 1 K for elds 5, 10, and 14 T.

This low tem perature state of $C \in O \ s_4 Sb_{12}$ is extrem ely sensitive to La-im purities. Just 2 % of La introduced for $C \in$ suppresses the anom aly to tem peratures lower than 0.4 K. (Fig. 2) There is an increase of C = T below 1 K, possibly related to this transition taking place at much lower tem peratures. There is also a relatively large decrease of the electronic speci c heat in the param agnetic state. In order to con m this result we have measured two di erent crystals with di erent masses. These sam – ples were approximately 7 mg (# 1) and 2 mg (# 2). Large scattering was due to a combination of a short time constant (), large background contribution, and a lack of averaging of severalm easurements at the sam e tem perature (perform ed for x = 0 and 0.02). Nevertheless, there





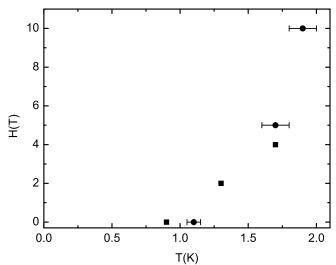


FIG. 3: Magnetic eld phase diagram of $CeO_{\$}Sb_{12}$. The transition temperatures were identi ed by the maximum values of C/T in Fig. 1 (dots). Squares represent the results of N am iki et al.⁸

is a good agreement between the two sets of data for x = 0.02, dem onstrating that our addenda subtraction is accurate. Moreover, this addenda is of the same magnitude for the pure sample and sample # 1, thus can not explain a large drop in C=T between x = 0 and 0.02. Further substitution of La for C e results in additional reduction of the speci c heat. This reduction, say at 3 K, is by more than 70 % for just 10 % of La. The 10 T m agnetic eld applied along the (100) direction suppresses the low temperature tail and reduces further obtained from the extrapolation of C=T versus T data to T = 0 (See Fig. 2 for 10 T data.)

A disappearance of the 1.1 K peak in the La-doped sam ples provides a com plem entary evidence for the intrinsic origin of this peak. La is chem ically sim ilar to C e but carries no f-electron. The substitution of La for C e leads to some random ness on f-electron sites. The low tem perature structure seem s to be characteristic of undoped, high quality sam ples only.

A similarly critical dependence on chemical disorder on the f-ion site was reported for $C \in A \downarrow .$ ¹³ In this latter case, however, La induces bulk magnetism, as opposed to the case of $C \in S_4 Sb_{12}$.

III. CONCLUSIONS

Our results point to a number of unusual features of the low tem perature behavior of CeO s₄Sb₁₂. First of all, the magnetic phase diagram shown in Fig. 3 is atypical of a Ce-based K ondo insulator or a heavy ferm ion system . A positive sign of dTm =dH is inconsistent with antiferrom agnetism. The tem perature variation of the susceptibility indicates the predom inance of an iferrom agnetictype interactions rather than ferrom agnetic.⁴ A lso, a low value of the susceptibility at 1.8 K argues against ferromagnetic character of the ordered state. As it was noticed by N am iki et al., this phase diagram is rem in iscent of $C \in B_6^{14}$ (or La-doped¹⁵ $C \in B_6$), which undergoes antiferroquadrupolar order. However, this type of order is inconsistent with a small entropy released below T_m and with the proposed crystalline electric eld (CEF) con quration of Ce in CeO s_4Sb_{12} . The CEF ground state of Ce^{3+} in a cubic environment can be either 7 doublet or 8 quartet. A tof the susceptibility versus tem perature seem s to indicate that 7 is the low est energy state.⁴ Furtherm ore, the excited $_8$ is 327 K above the CEF ground state. How ever, 7 does not possess a quadrupolar electric m om ent. Thus, neutron scattering m easurem ents are needed to verify the CEF con guration of Ce in this com pound.

O ur results dem onstrate a strong correlation between the electronic speci cheat coe cient of the param agnetic state and the presence of the low tem perature anom aly. Less perfect sam ples, containing sm all am ounts of La, have both reduced and suppressed transition to the ordered state with respect to the pure com pound. This behavior strongly suggests that enhanced is an intrinsic property of C eO s_4Sb_{12} and that the 1.1 K transition has itinerant character. Sm all entropy rem oved is also consistent with this itinerant character of the transition. T herefore, the reported insulating-like resistivity rem ains a puzzle.

A cknow ledgm ents

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andraka@physu .edu

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